

UNR2211/2212/2213/2214/2215/2216/2217/2218/2219/2210/ 221D/221E/221F/221K/221L/221M/221N/221T/221V/221Z

(UN2211/2212/2213/2214/2215/2216/2217/2218/2219/2210/ 221D/221E/221F/221K/221L/221M/221N/221T/221V/221Z)

Silicon NPN epitaxial planer transistor

For digital circuits

■ Features

- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- Mini type package, allowing downsizing of the equipment and automatic insertion through tape packing and magazine packing.

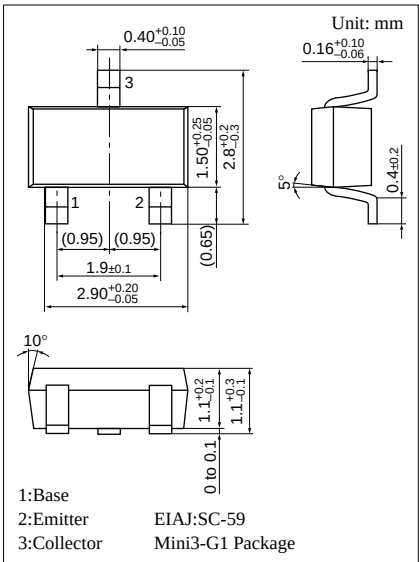
■ Resistance by Part Number

	Marking Symbol	(R ₁)	(R ₂)
• UNR2211	8A	10kΩ	10kΩ
• UNR2212	8B	22kΩ	22kΩ
• UNR2213	8C	47kΩ	47kΩ
• UNR2214	8D	10kΩ	47kΩ
• UNR2215	8E	10kΩ	—
• UNR2216	8F	4.7kΩ	—
• UNR2217	8H	22kΩ	—
• UNR2218	8I	0.51kΩ	5.1kΩ
• UNR2219	8K	1kΩ	10kΩ
• UNR2210	8L	47kΩ	—
• UNR221D	8M	47kΩ	10kΩ
• UNR221E	8N	47kΩ	22kΩ
• UNR221F	8O	4.7kΩ	10kΩ
• UNR221K	8P	10kΩ	4.7kΩ
• UNR221L	8Q	4.7kΩ	4.7kΩ
• UNR221M	EL	2.2kΩ	47kΩ
• UNR221N	EX	4.7kΩ	47kΩ
• UNR221T	EZ	22kΩ	47kΩ
• UNR221V	FD	2.2kΩ	2.2kΩ
• UNR221Z	FF	4.7kΩ	22kΩ

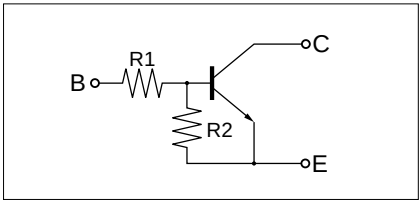
■ Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	50	V
Collector to emitter voltage	V _{CEO}	50	V
Collector current	I _C	100	mA
Total power dissipation	P _T	200	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{sig}	-55 to +150	°C

Note) The part numbers in the parenthesis show conventional part number.



Internal Connection



UNR2211/2212/2213/2214/2215/2216/2217/2218/2219/2210/
Transistors with built-in Resistor 221D/221E/221F/221K/221L/221M/221N/221T/221V/221Z

■ Electrical Characteristics (T_a=25°C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Collector cutoff current		I _{CBO}	V _{CB} = 50V, I _E = 0			0.1	μA
		I _{CEO}	V _{CE} = 50V, I _B = 0			0.5	μA
Emitter cutoff current	UNR2211	I _{EBO}	V _{EB} = 6V, I _C = 0			0.5	mA
	UNR2212/2214/221E/221D/221M/221N/221T					0.2	
	UNR2213					0.1	
	UNR2215/2216/2217/2210					0.01	
	UNR221F/221K					1.0	
	UNR2219					1.5	
	UNR2218/221L/221V					2.0	
	UNR221Z					0.4	
Collector to base voltage		V _{CBO}	I _C = 10μA, I _E = 0	50			V
Collector to emitter voltage		V _{CEO}	I _C = 2mA, I _B = 0	50			V
Forward current transfer ratio	UNR2211	h _{FE}	V _{CE} = 10V, I _C = 5mA	35			
	UNR2212/221E			60			
	UNR2213/2214/221M			80			
	UNR2215*/2216*/2217*/2210*			160		460	
	UNR221F/221D/2219			30			
	UNR2218/221K/221L			20			
	UNR221N/221T			80		400	
	UNR221V			60		200	
	Collector to emitter saturation voltage			V _{CE(sat)}	I _C = 10mA, I _B = 0.3mA		
UNR221V	I _C = 10mA, I _B = 1.5mA		0.04		0.25		
Output voltage high level		V _{OH}	V _{CC} = 5V, V _B = 0.5V, R _L = 1kΩ	4.9			V
Output voltage low level		V _{OL}	V _{CC} = 5V, V _B = 2.5V, R _L = 1kΩ			0.2	V
UNR2213/221K	V _{CC} = 5V, V _B = 3.5V, R _L = 1kΩ				0.2		
UNR221D	V _{CC} = 5V, V _B = 10V, R _L = 1kΩ				0.2		
UNR221E	V _{CC} = 5V, V _B = 6V, R _L = 1kΩ				0.2		
Transition frequency		f _T	V _{CB} = 10V, I _E = -2mA, f = 200MHz		150		MHz
Input resistance	UNR2211/2214/2215/221K	R _i		(−30%)	10	(+30%)	kΩ
	UNR2212/2217/221T				22		
	UNR2213/221D/221E/2210				47		
	UNR2216/221F/221L/221N/221Z				4.7		
	UNR2218				0.51		
	UNR2219				1		
	UNR221M/221V				2.2		

* h_{FE} rank classification (UNR2215/2216/2217/2210)

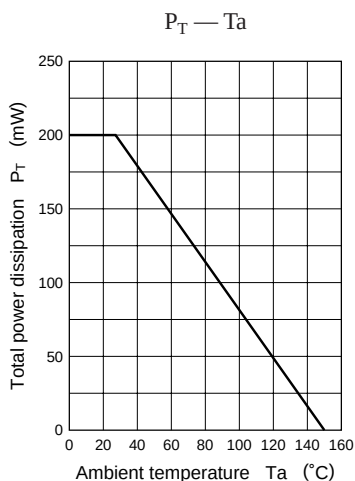
Rank	Q	R	S
h _{FE}	160 to 260	210 to 340	290 to 460

UNR2211/2212/2213/2214/2215/2216/2217/2218/2219/2210/
Transistors with built-in Resistor 221D/221E/221F/221K/221L/221M/221N/221T/221V/221Z

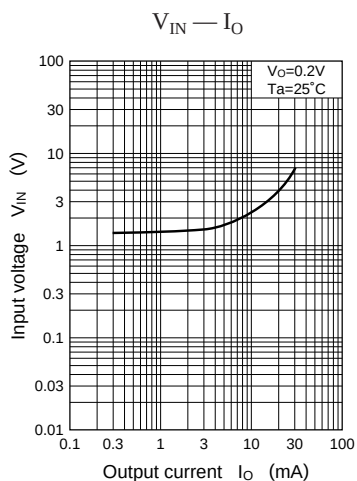
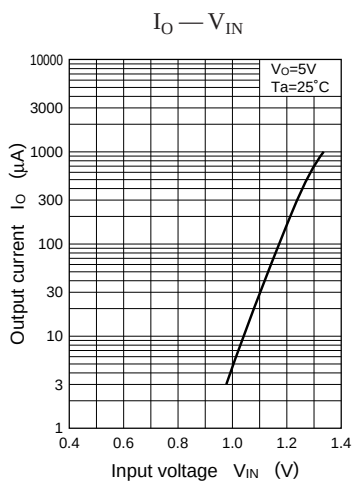
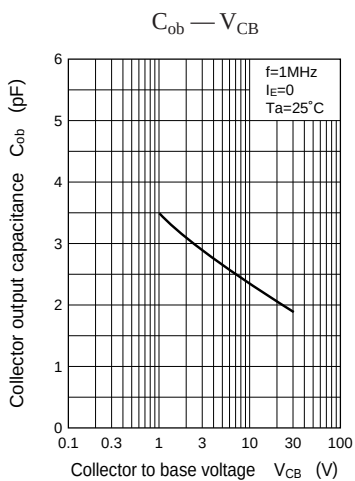
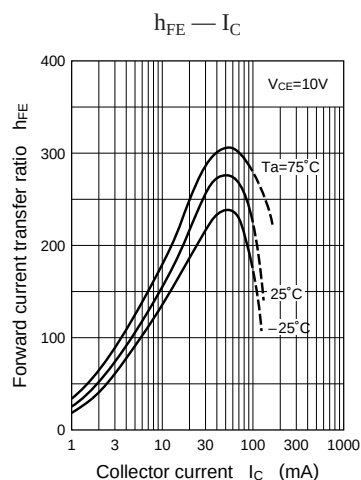
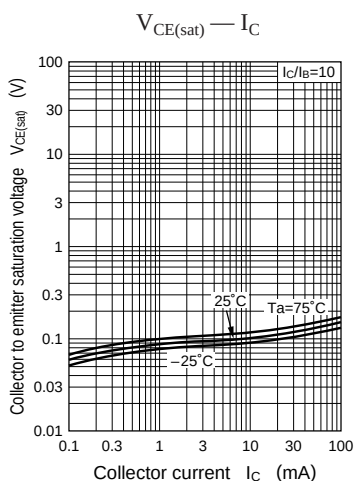
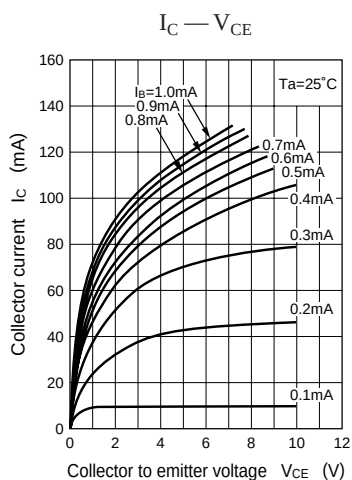
■ Electrical Characteristics (continued) (Ta=25°C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Resis- tance ratio	UNR2211/2212/2213/221L	R_1/R_2		0.8	1.0	1.2	
	UNR2214			0.17	0.21	0.25	
	UNR2218/2219			0.08	0.1	0.12	
	UNR221D				4.7		
	UNR221E				2.14		
	UNR221F/221T				0.47		
	UNR221K				2.13		
	UNR221M				0.047		
	UNR211N				0.1		
	UNR211V				1.0		
	UNR211Z				0.21		

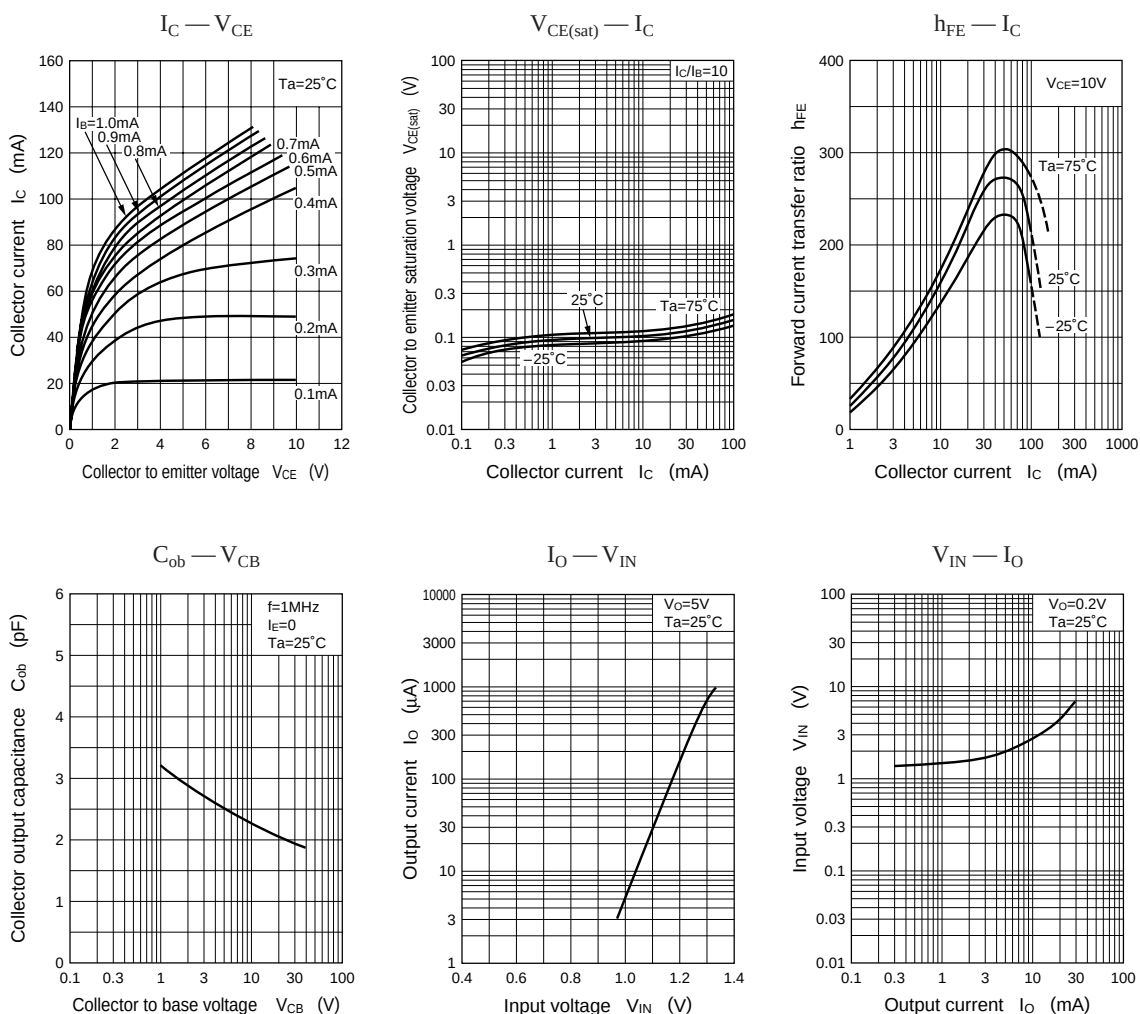
Common characteristics chart



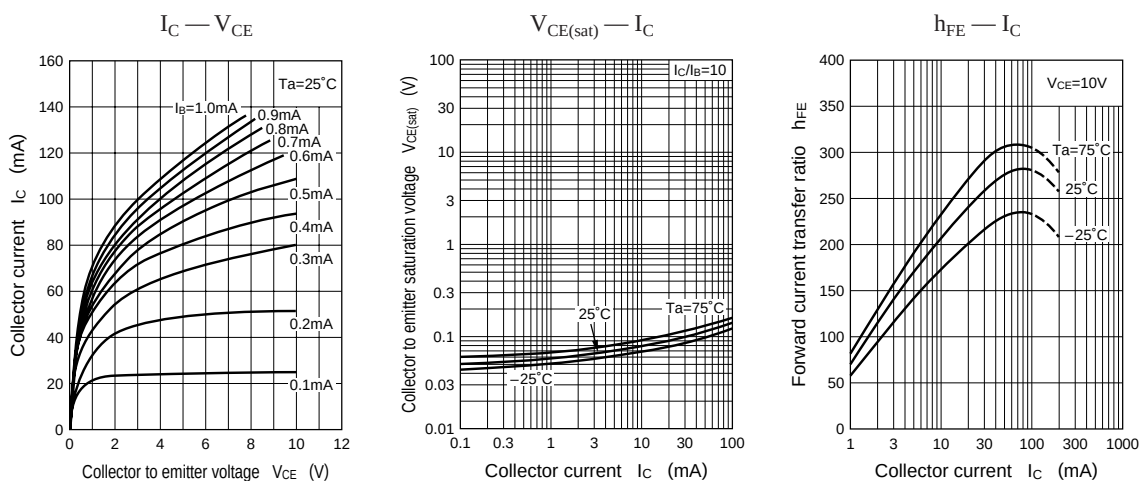
Characteristics charts of UNR2211

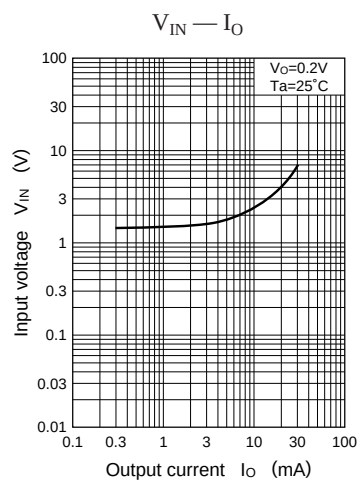
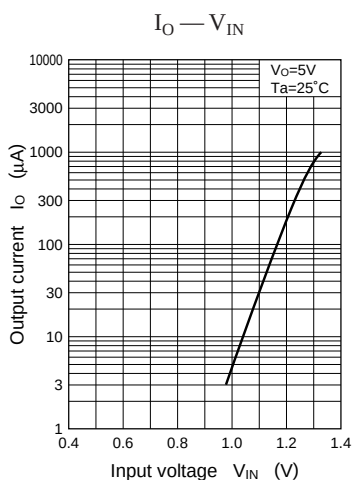
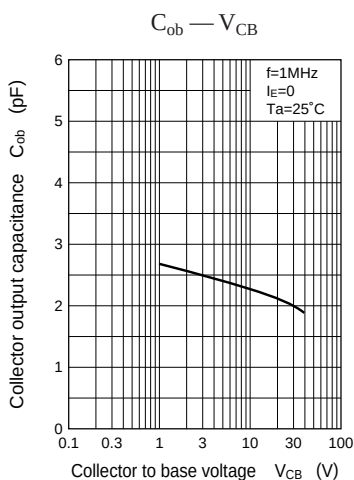


Characteristics charts of UNR2212

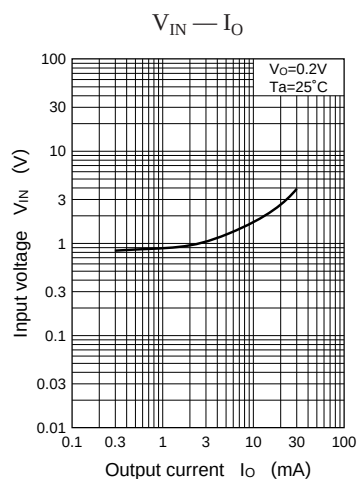
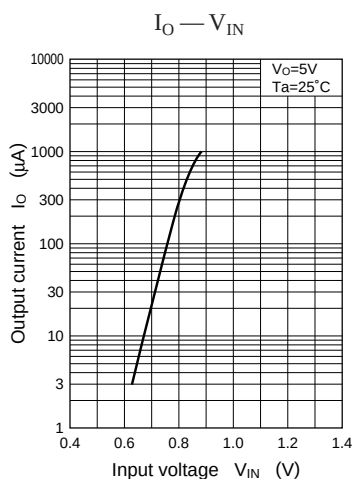
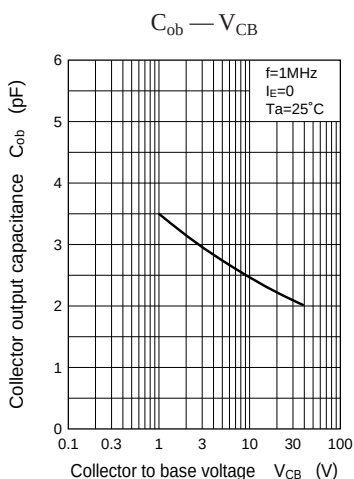
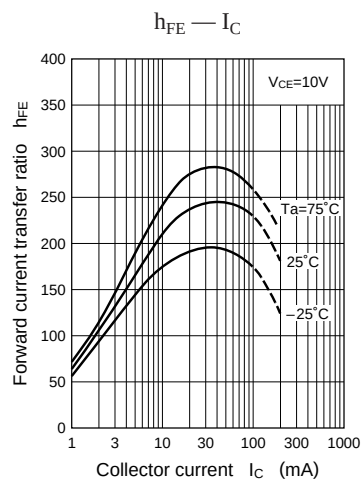
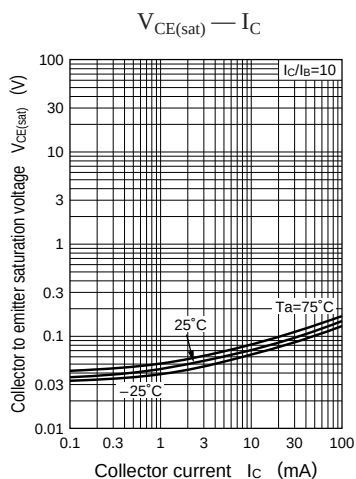
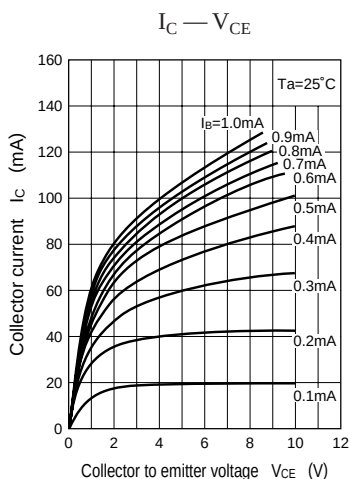


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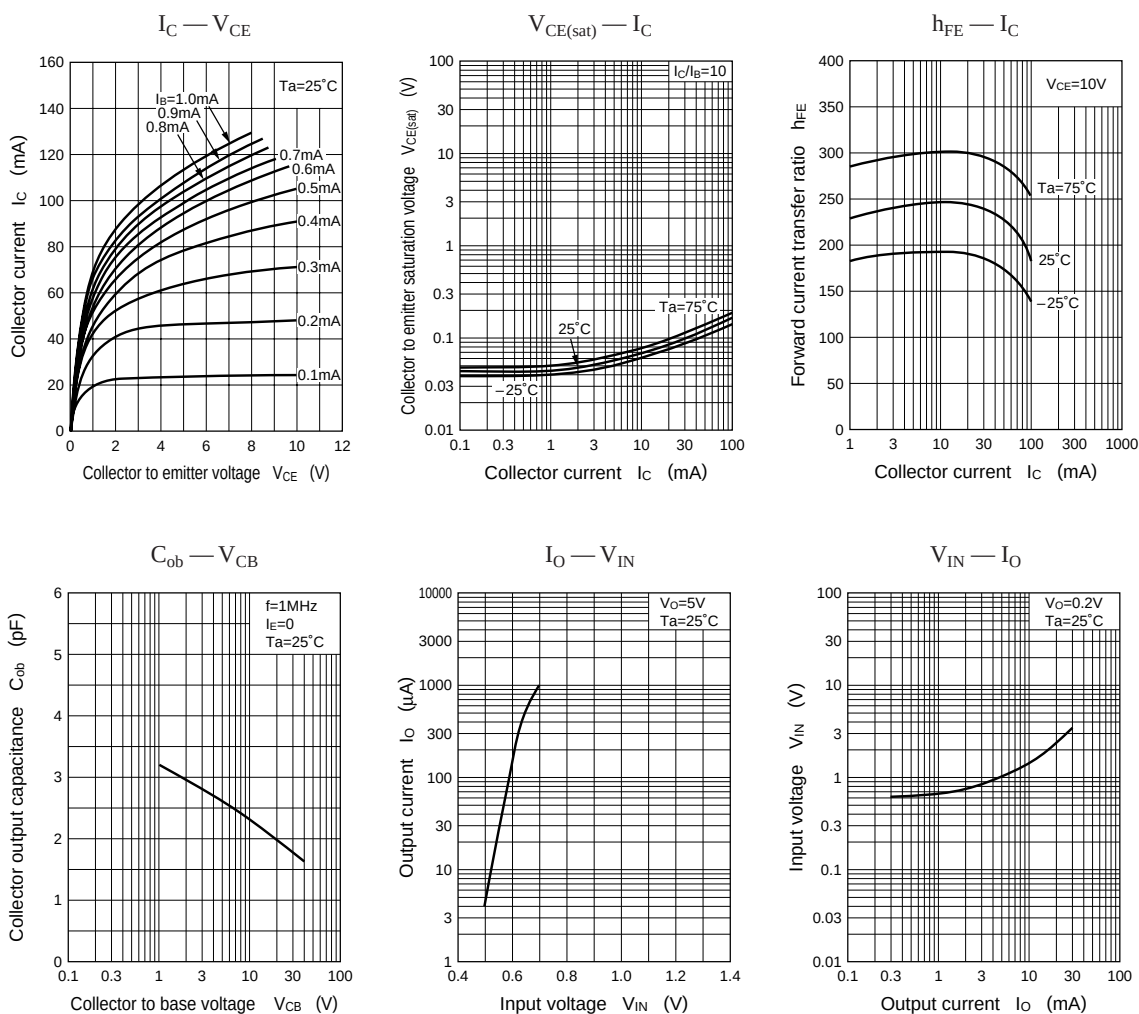




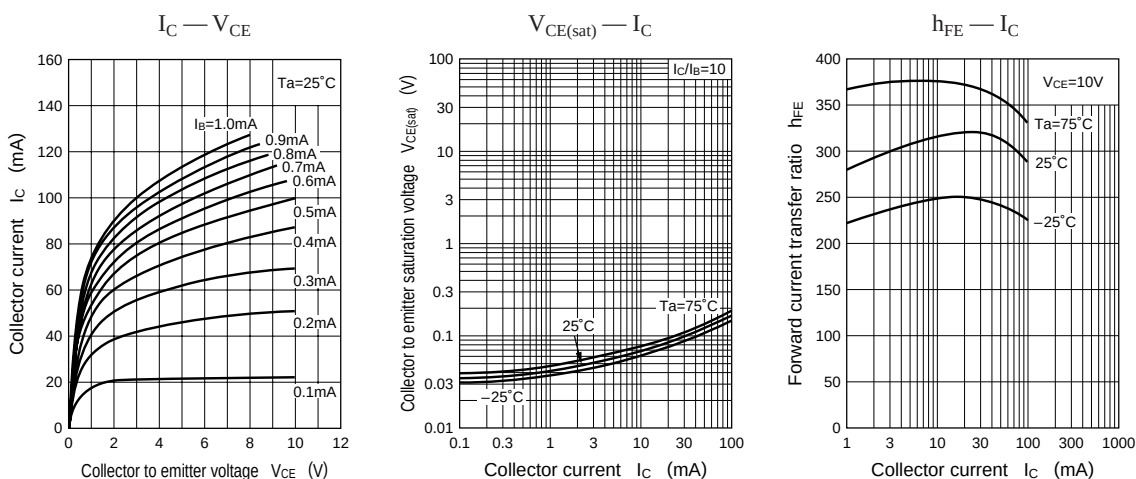
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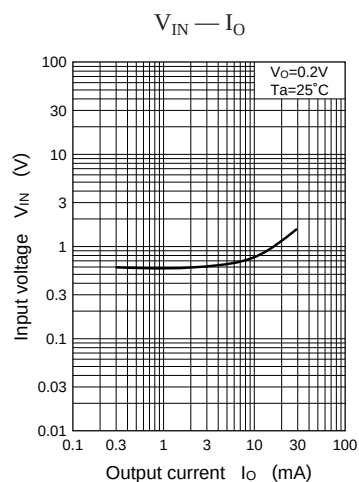
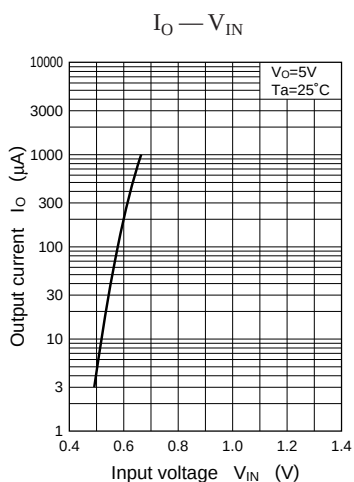
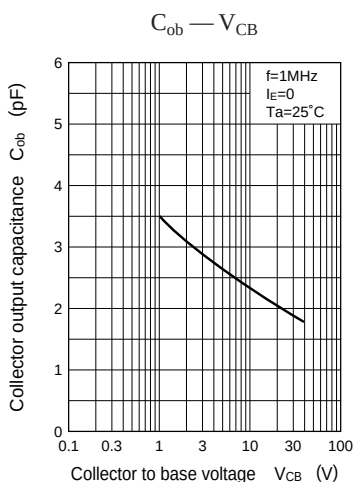


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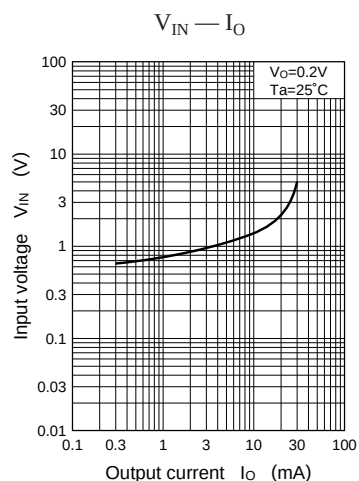
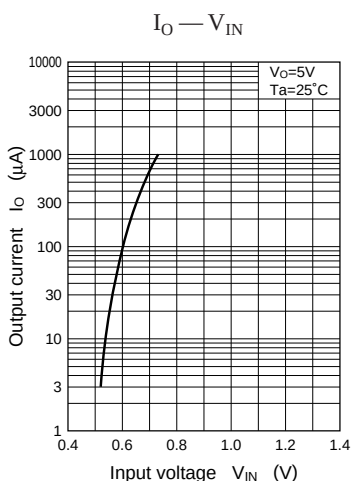
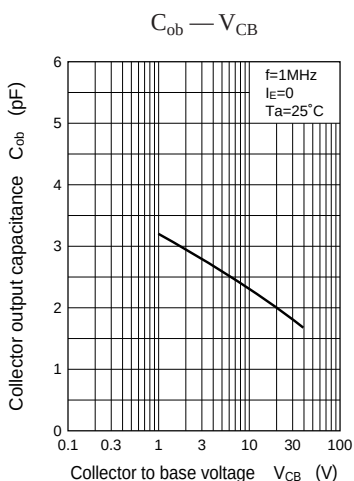
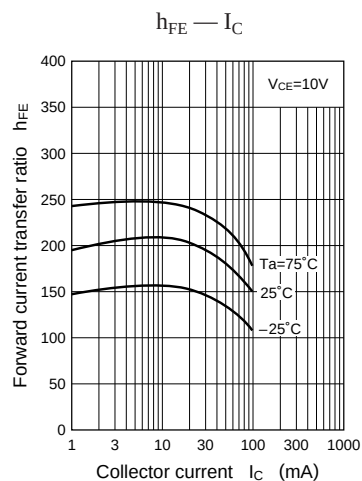
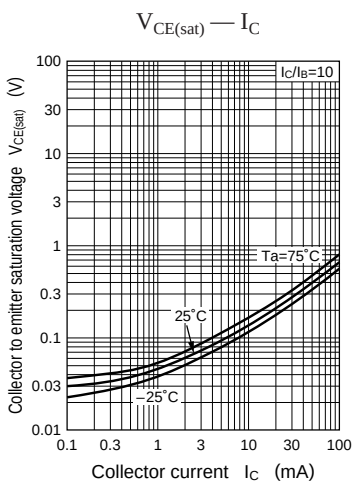
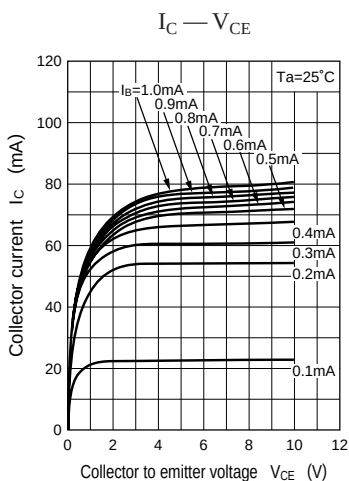


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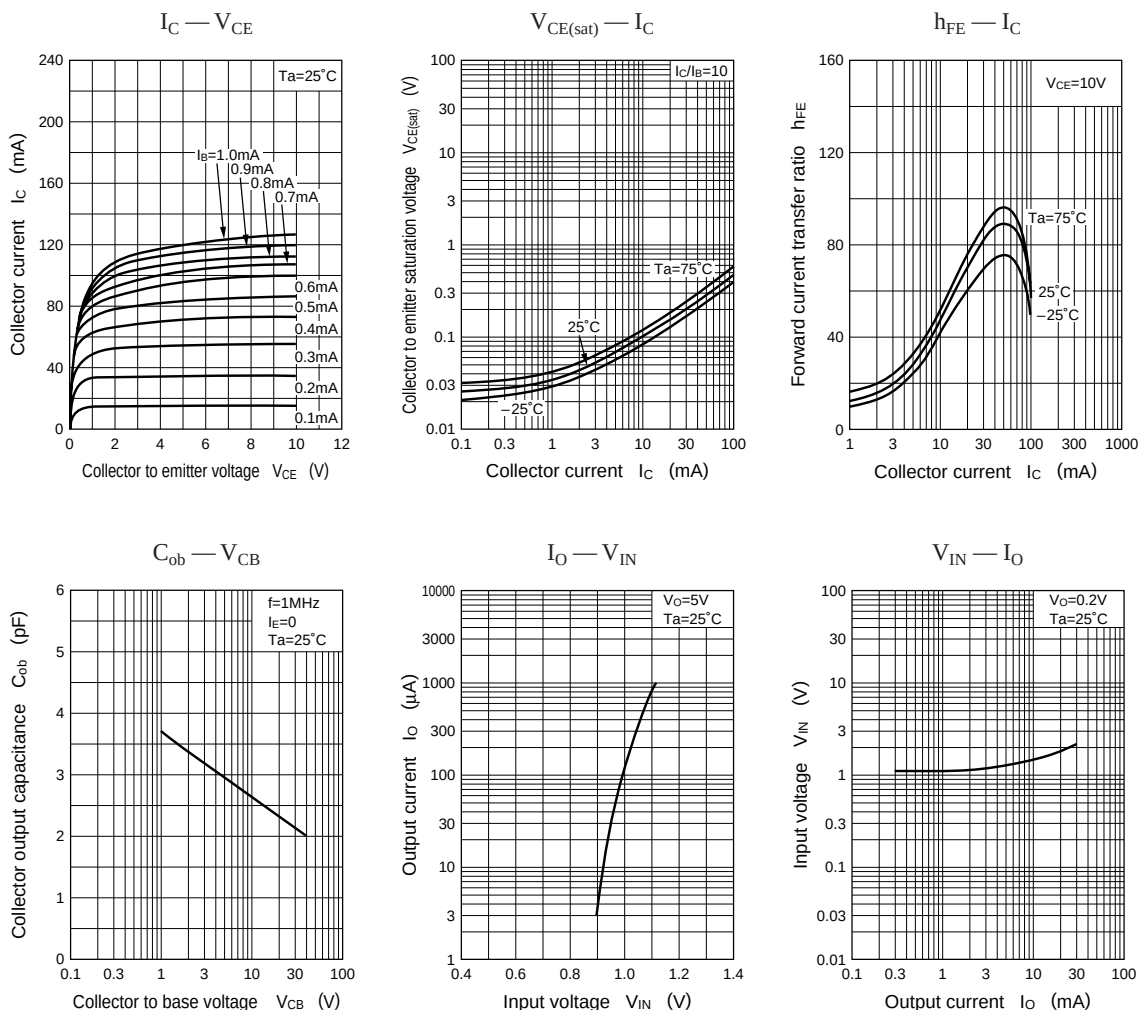




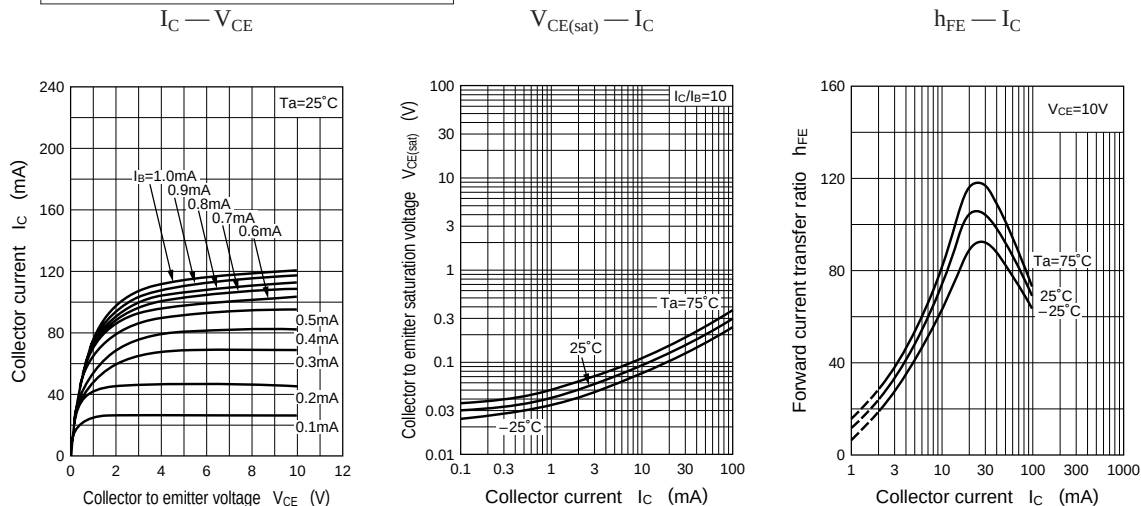
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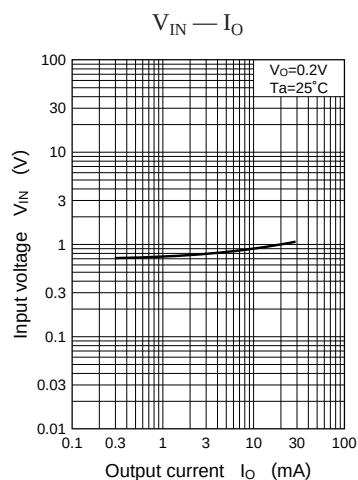
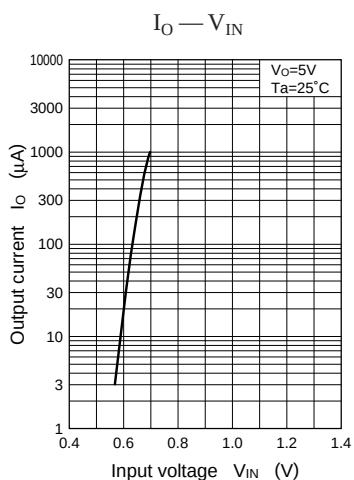
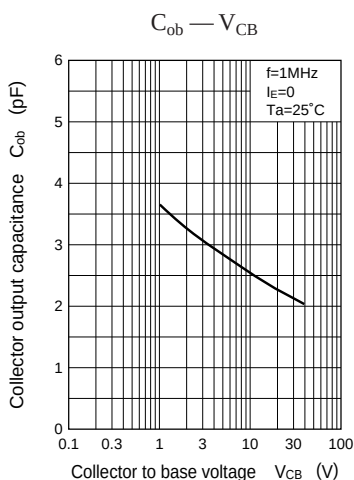


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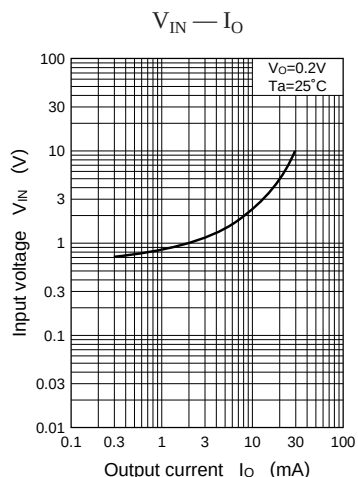
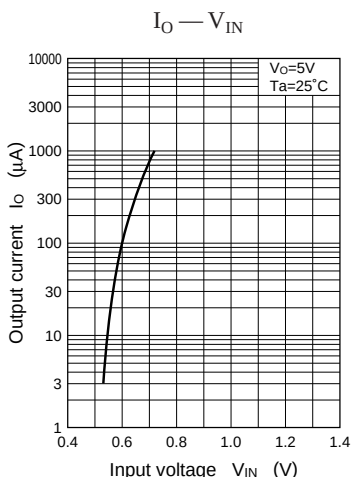
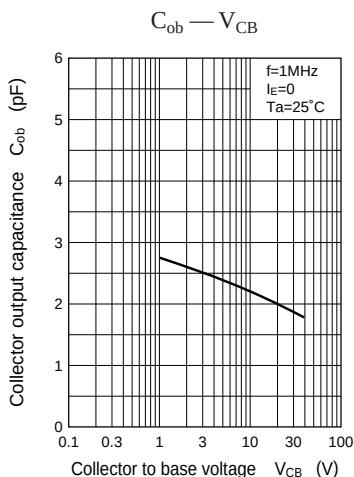
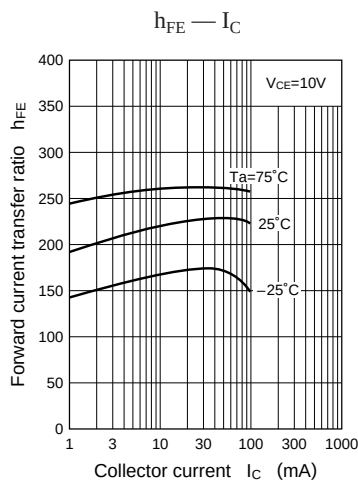
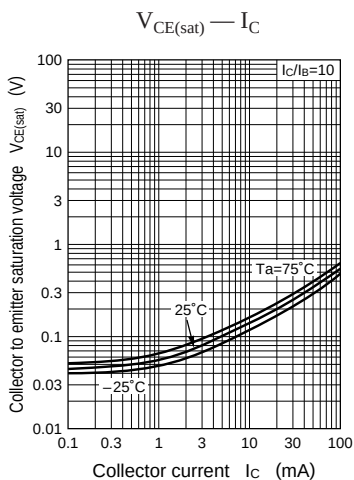
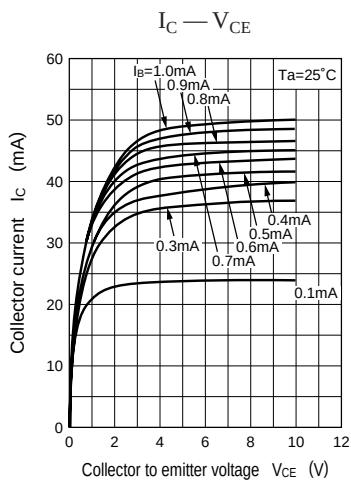


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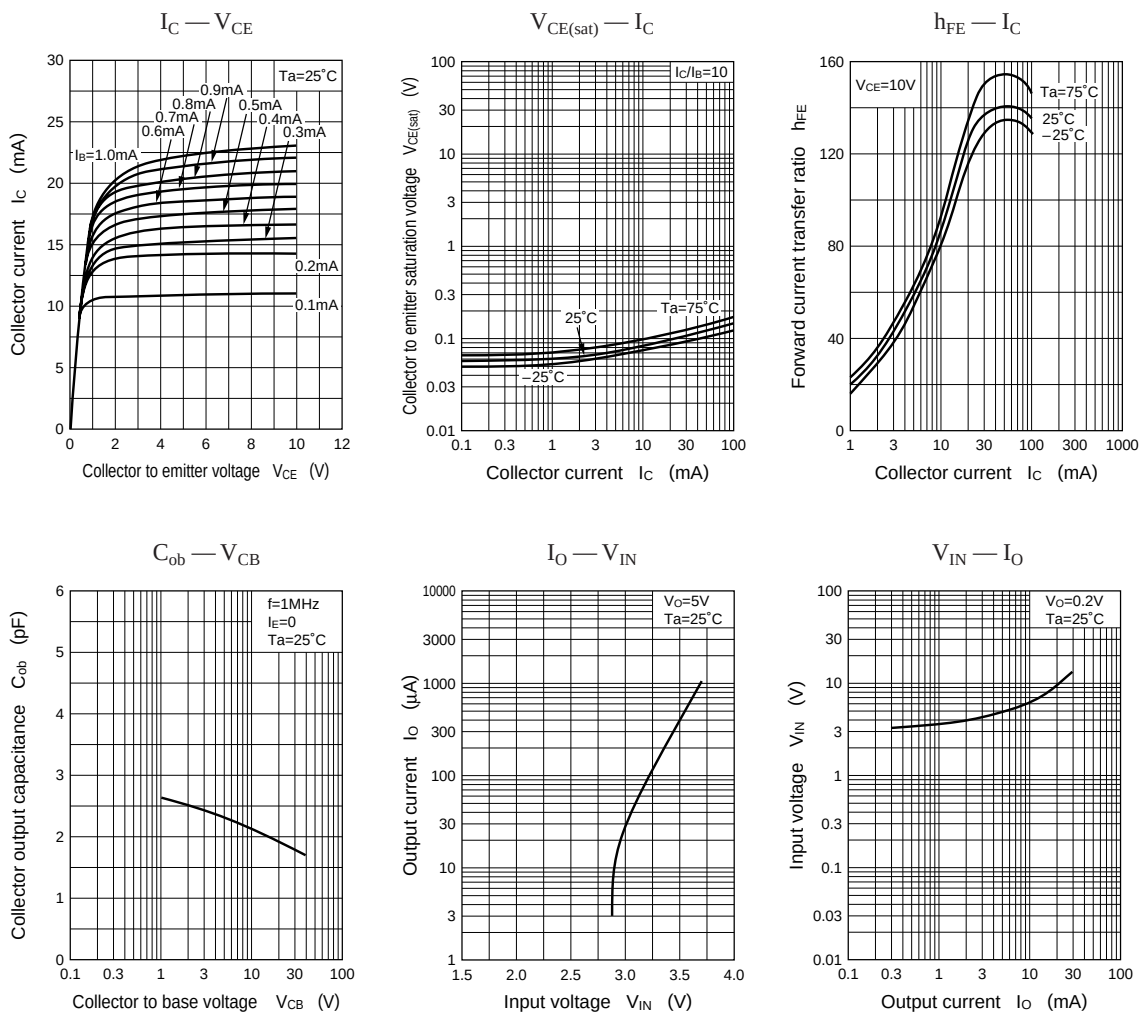




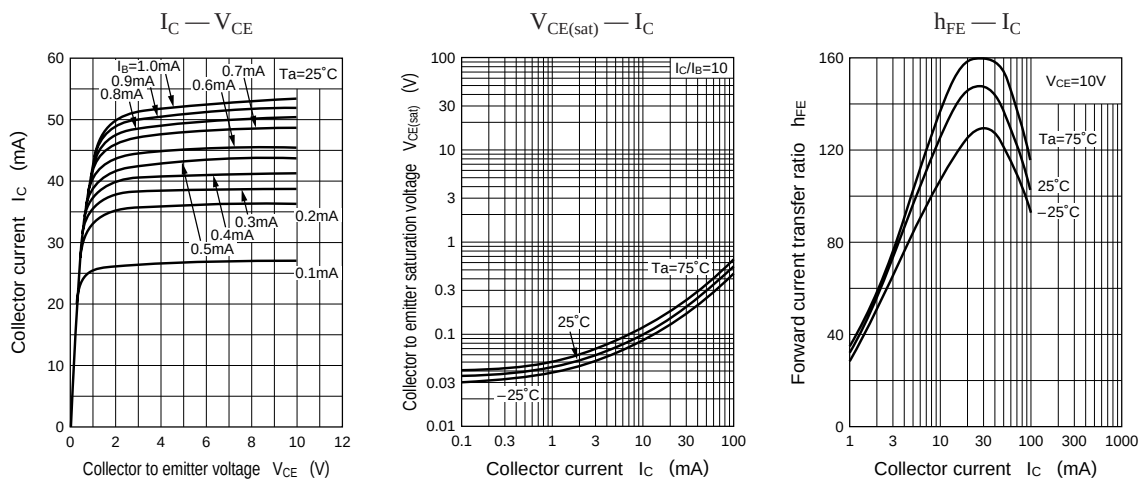
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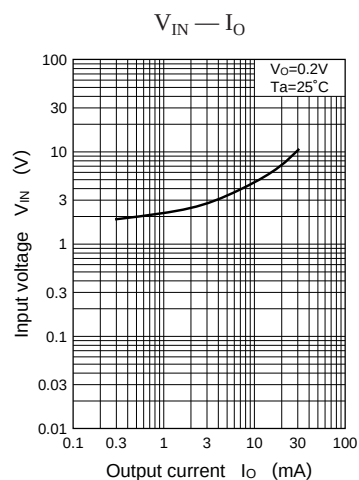
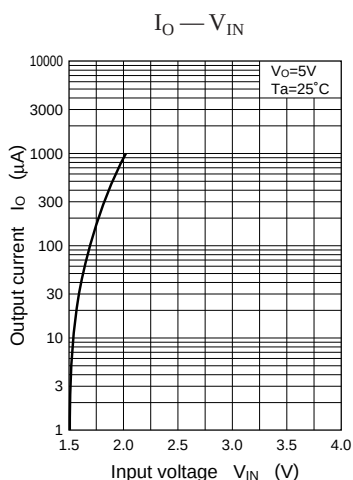
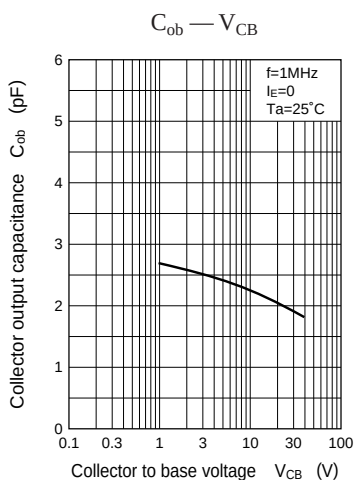


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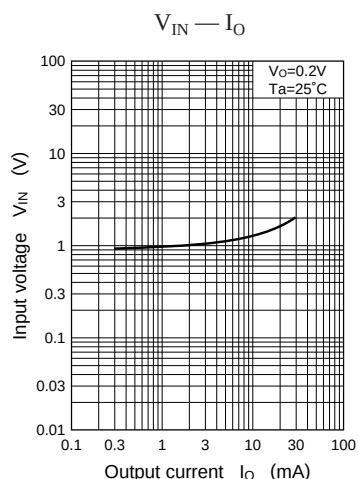
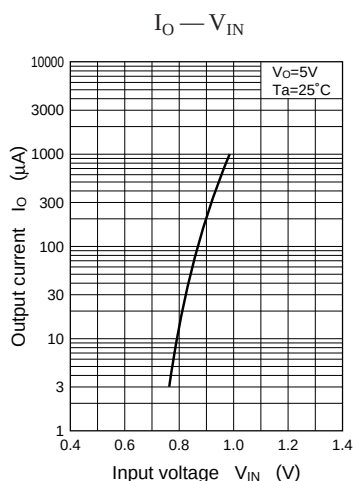
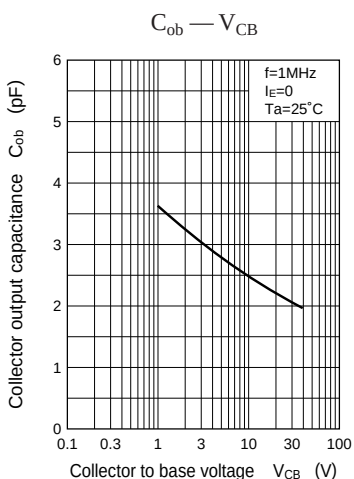
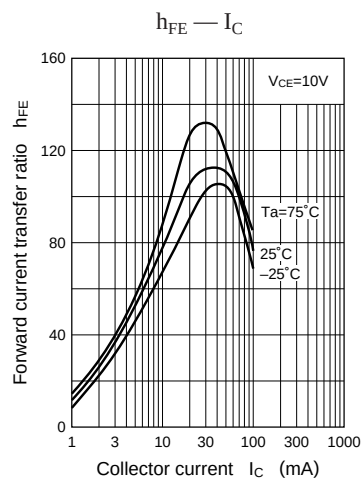
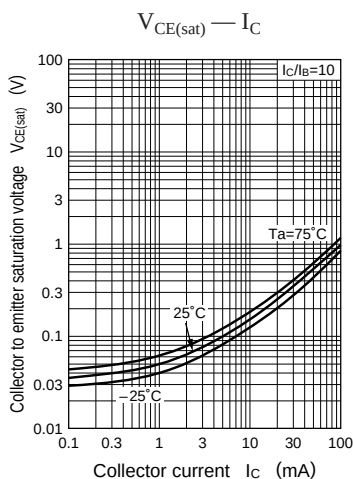
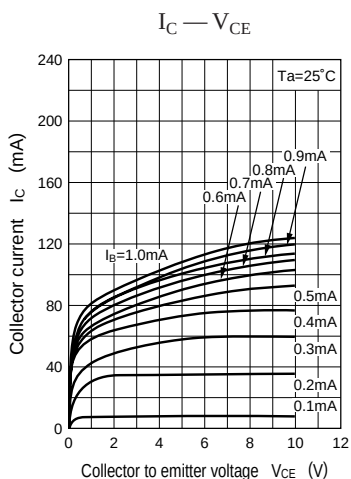


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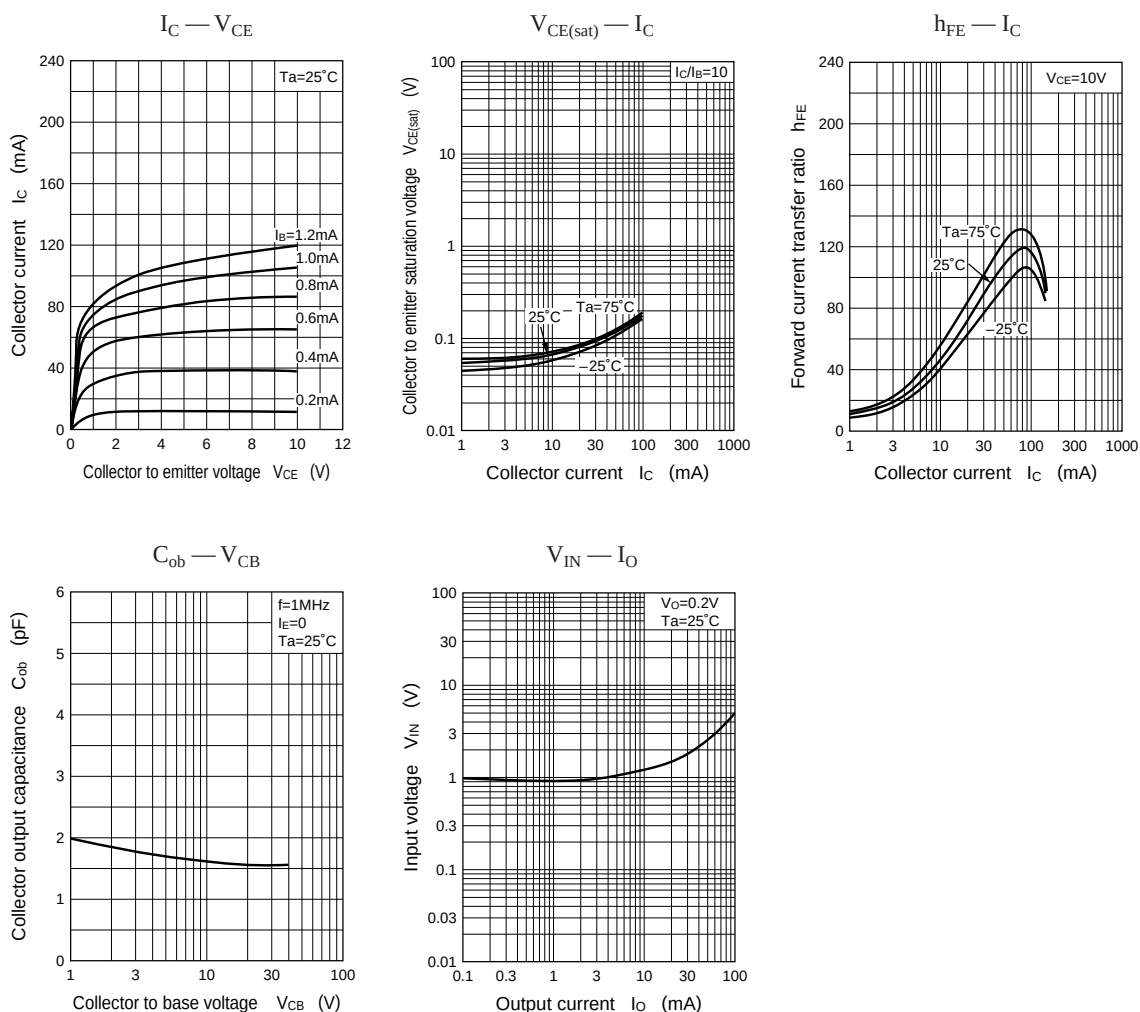




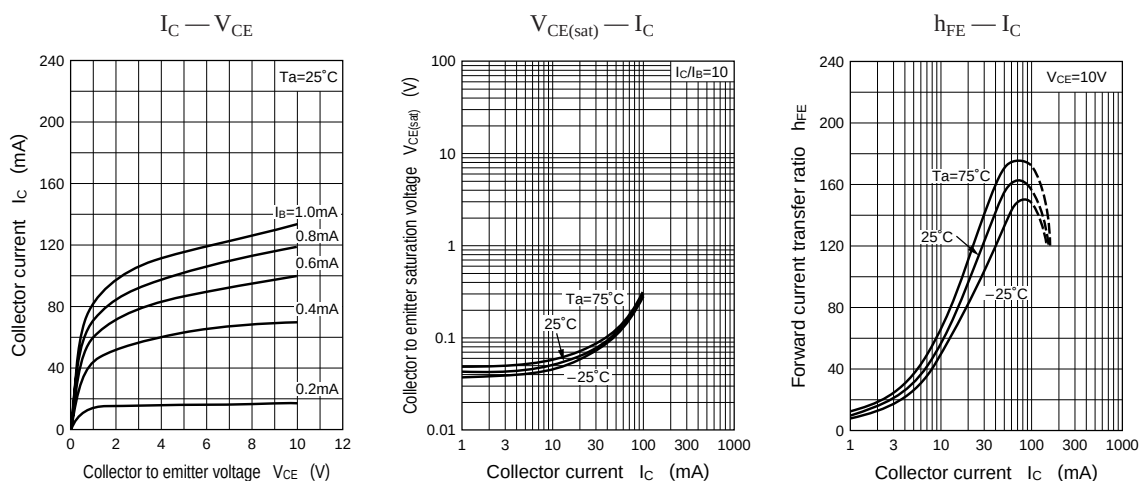
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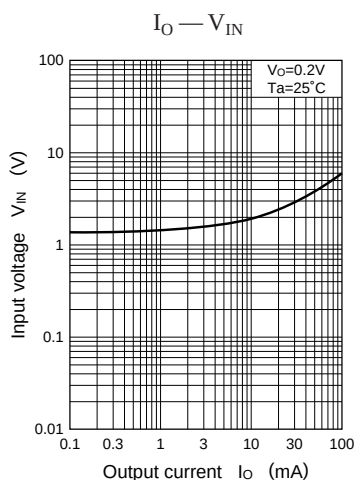
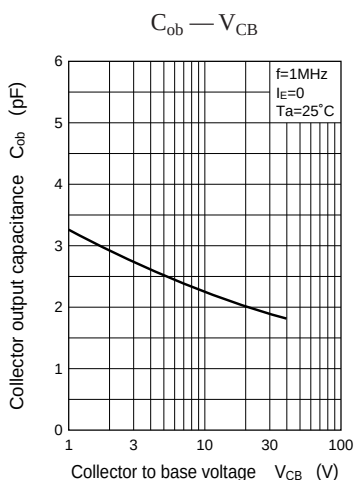


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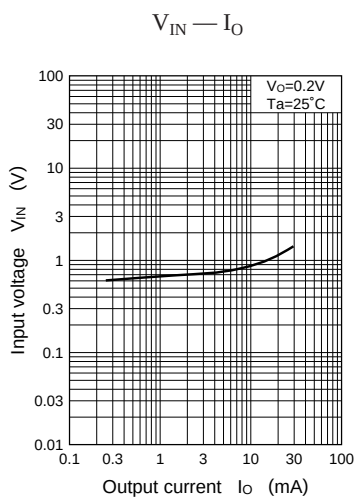
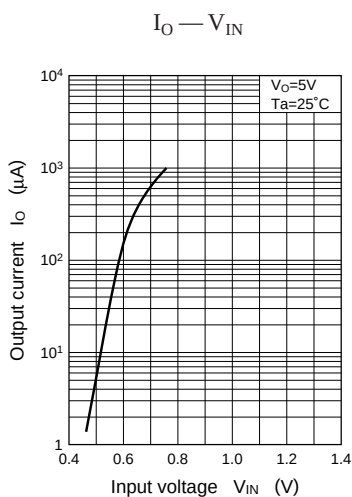
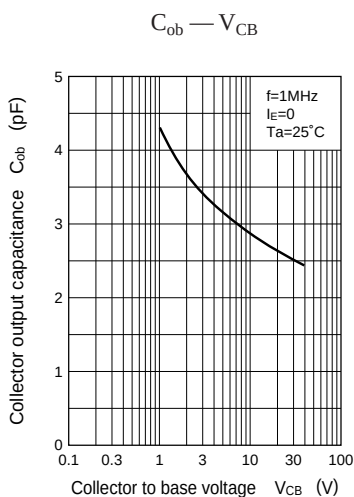
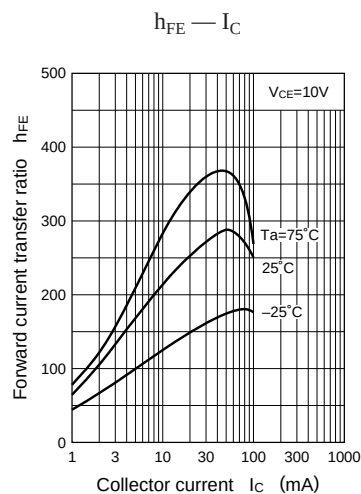
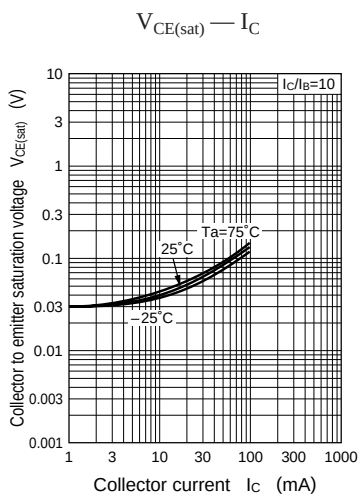
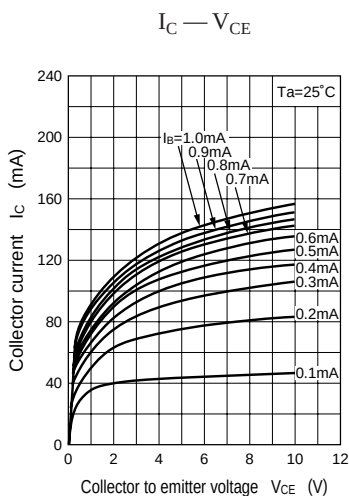


Characteristics charts of UNR221L

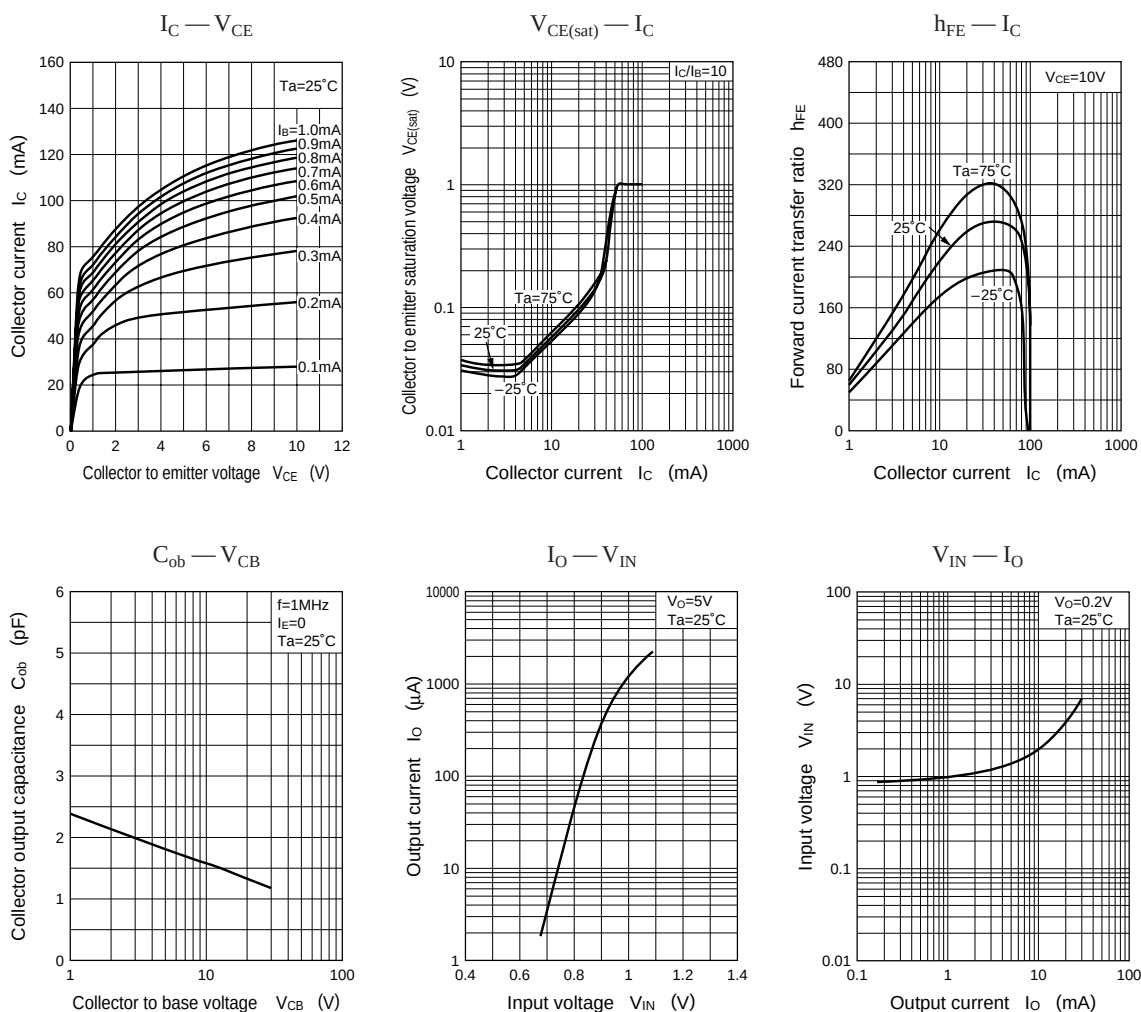




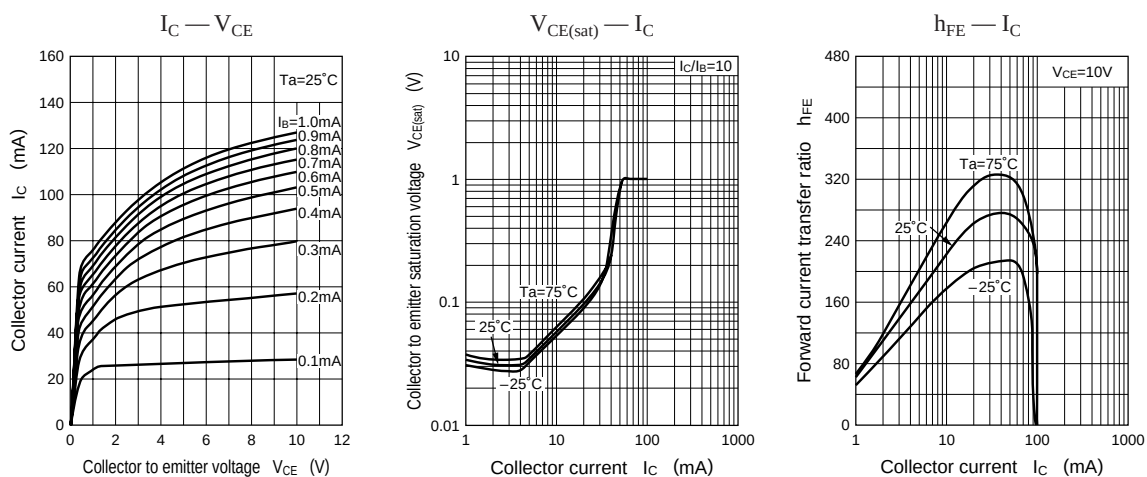
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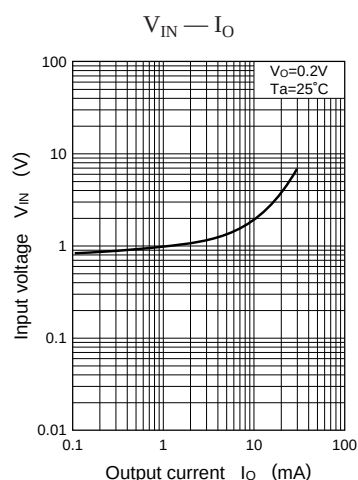
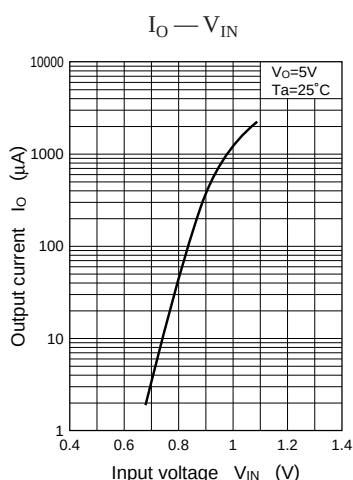
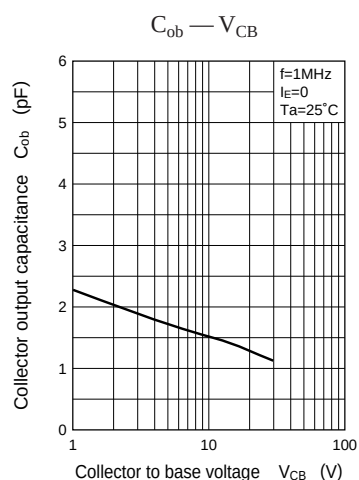


Characteristics charts of UNR221N

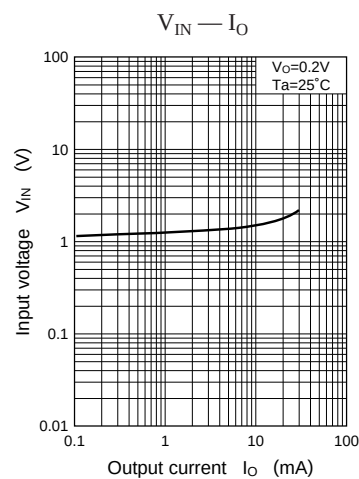
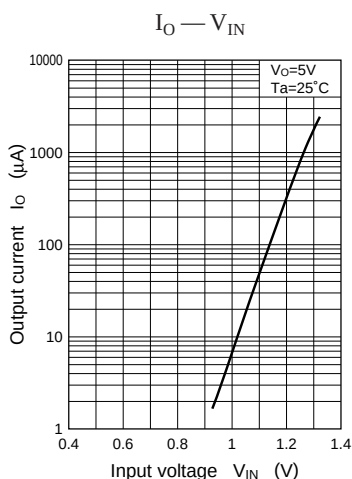
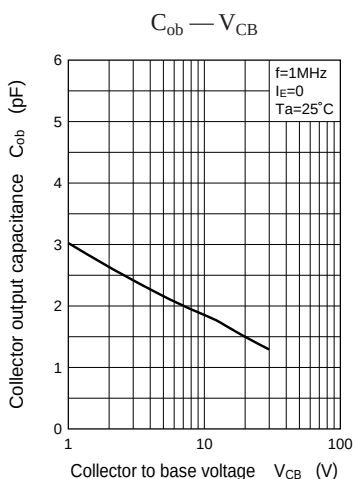
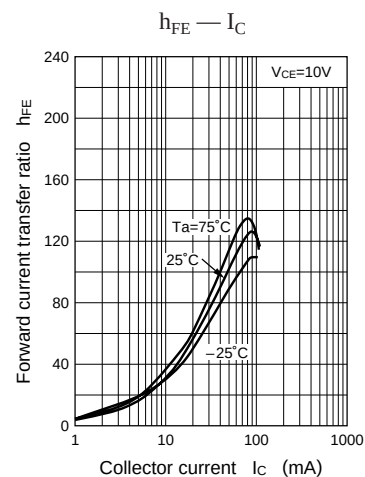
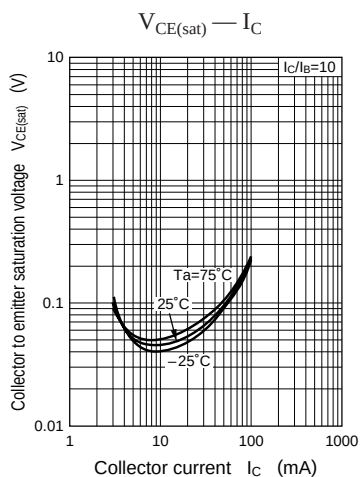
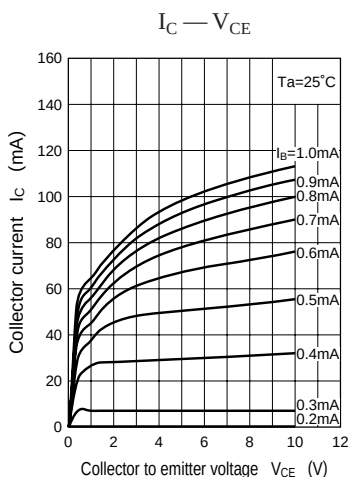


Characteristics charts of UNR221T

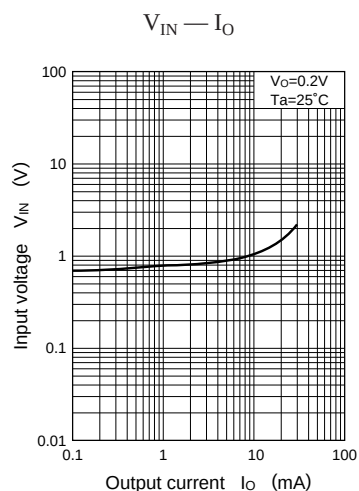
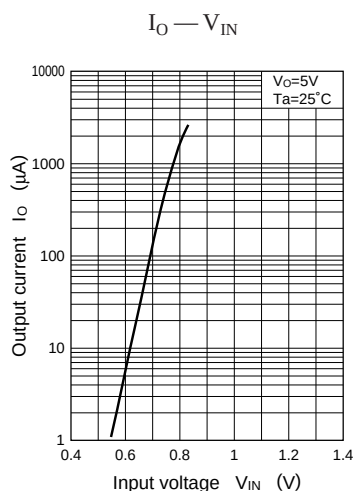
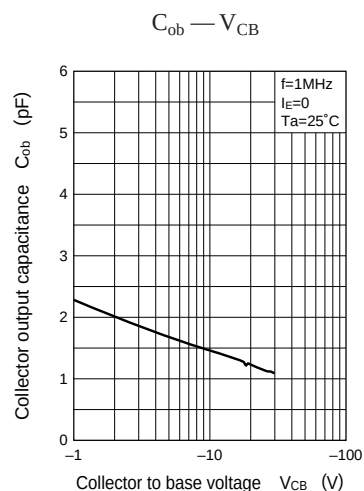
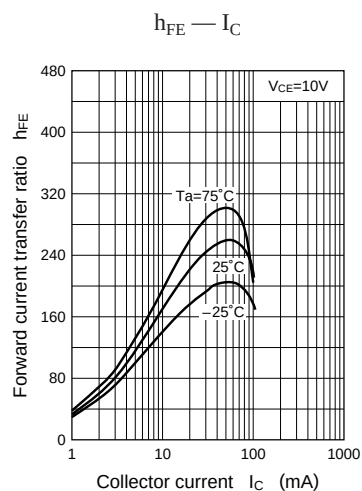
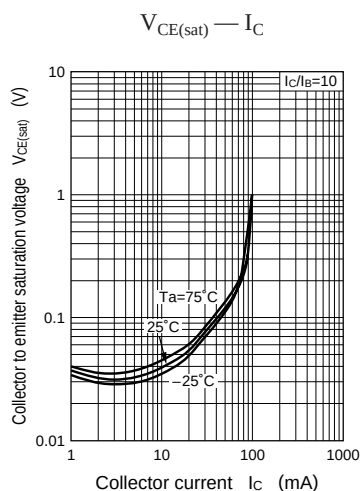
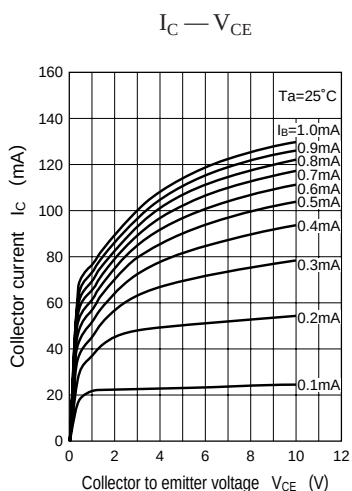




Characteristics charts of UNR221V



Characteristics charts of UNR221Z



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